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Influence of Transition Metal Doping on the Structural and Electronic Behaviour of Quaternary Double Perovskite, Cs₂AgInCl₆, using First-Principles Calculations

I. B. Ogunniranye¹, O. E. Oyewande¹, T. Atsue^{1,2} and M. Usikalu³

¹ Department of Physics, Faculty of Science, University of Ibadan, Ibadan, Nigeria.
²Department of Physics, Faculty of Physical Science, Federal University Dutsin-Ma, Katsina, Nigeria.

³ Department of Physics, College of Science and Technology, Covenant University, Ota, Nigeria.

ib.ogunniranye@ui.edu.ng; oe.oyewande@ui.edu.ng; tastue@fudutsinma.edu.ng

Abstract. Recently, direct bandgap double perovskites are becoming more popular among researchers in the photovoltaic community owing to their potential to address issues of lead (Pb) toxicity and structural instability inherent in lead halide (simple) perovskites. In this study, In-Ag based direct bandgap double perovskite, $Cs_2AgInCl_6$ (CAIC), is treated with transition metal doping to improve its material properties. Investigations of structural and electronic properties of Cu-doped CAIC, $Cs_2Ag_{1-x}Cu_xInCl_6$, are done using ab-initio calculations with density functional theory (DFT) and virtual crystal approximation (VCA). With the introduction of Cu-dopant, obtained results show improvement in the structural and electronic behaviour of CAIC. Based on obtained results, transition metal (Cu) doping is a viable means of treating double perovskites - by tuning their material properties suitable for an extensive range of photovoltaics, solar cells and optoelectronics.

Keywords: Virtual crystal approximation; DFT; solid solution; optimized lattice parameter; Cu-doping.

1. Introduction

Perovskite solar cells (PSCs) havegarnered much attentionas promising photovoltaic device capable of harnessing solar power effectively owing to high power conversion efficiency (PCE) of about 25.2%[1], materials availability, ease of fabrication process and low cost[2]–[8]. Methylammonium lead tri-iodide (CH₃NH₃PbI₃ or MAPI), atypical lead halide perovskite (LHP), is gaining popularity as an ideal light harvester and a charge carrier mediator in solar cells[3], [9], [10], because of its appealing characteristics such as;optimal direct bandgap (~1.5 eV), good photoconductivity, considerable lifetime diffusion length, high optical absorption coefficient, great bipolar transporting capability, defect tolerance ability, and low carrier effective masses with high mobility [11]–[20]. Despite these appealingqualities, MAPI still faces some fundamental issues of instability and toxicity associated with lead (Pb)[21]–[23], which have hindered their large scale commercialization as viable PSCs.

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Substitution of toxic Pb with non-toxic elements is considered one of the viable means of resolving these issues and has subsequently led to the search for Pb-free perovskites and perovskite-derivatives materials. One way of achieving this is through direct substitution of Pb²⁺ with non-toxic group IV elements such as tin (Sn) andgermanium (Ge). Unfortunately, these produced undesirable characteristics such as poor stability and low performance of PSCs attributed to the oxidation of Ge²⁺ and Sn²⁺ to their 4+ states [24]–[26]. Another approach involves the complex substitution of Pb²⁺ wherein Pb²⁺ cation is replaced with monovalent and trivalent cations resulting in a new structure known as double perovskite (DP) [27]. DP has the generalA₂M[']M^{''}X₆ stoichiometry, where A represents cation like Cs⁺, M['] denotesmonovalent cation (M['] = Ag⁺, Cu⁺)and M^{''} trivalent cation (M^{''} = In³⁺, Bi³⁺), while X halides [28].

In recent times, DPs are increasingly gaining popularity among researchers in the photovoltaic research community owing to their potential to address issues of structural instability and toxicity associated with toxic lead (Pb) [28], [29]. Direct bandgap DPs are in the forefront following the pioneering work by Volonakis and co-workers in 2017 where $Cs_2AgInCl_6$ (CAIC) DP was proposed, synthesized and identified as a potential, environmentally-benign replacement for lead-based halide perovskites for applications in photovoltaic, solar cells and optoelectronics[30].CAIC is a direct-bandgap DP with high thermal and mechanical stabilities, which crystallizes in the face-centred cubic structure with space group Fm $\overline{3}$ m, and has an experimental lattice parameter of 10.469 – 10.481 Å and bandgap of 2.5 - 3.3 eV [30]–[32]. However, pure bulk CAIC crystal or powder are characterized with low photoluminescence quantum yield (PLQY) and photo-absorption coefficient compared to CAIC nanocrystals and these are as a result of parity-induced forbidden transition [31], [33], [34].

Experimental findings have shown doping engineering as a fundamental means to enhance the electronic and optical properties of materials, thereby enabling their widespread usability beyond photovoltaic applications. Recent experimental studies of M-cation doping of CAIC with transition metals have been observed to improve the electronic, photoluminescence quantum yield (PLQY) and photo-absorption coefficients of CAIC [33], [35]. Specifically, Cu-doping has shown to be effective enhancing the photoluminescence and thermoelectric properties of materials[36], [37]. Several simulation studies of the dynamics of surfaces of materials at nanoscales had been performed using different simulation methods [38]–[42], which show potential fabrication methods for optoelectronic devices and panel surfaces. Theoretical studies based on DFT on M-cation doping in double perovskites are scarce. Given these, this work seeks to investigate the effect of Cu-doping on the structural and electronic behaviour of CAIC ($Cs_2Ag_{1-x}Cu_xInCl_6$) using the virtual crystal approximation (VCA) approach within the framework of DFT. VCA is a first-principles technique in modelling disordered solid solutionsvia pseudopotential averaging [43]. Itis effective in treating disordered systems [43], [44].

2. ComputationalMethods

The electronic structures of $Cs_2Ag_{1-x}Cu_xInCl_6$ (CAIC:Cu) solid solutionswere examined using ab-initio calculation with the virtual crystal approximation (VCA) approach[45].DFT calculations were performed using Quantum ESPRESSO (QE) software package[46], [47], with

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the pseudopotential plane-wave method. The generalized gradient approximation of Perdew-Berke-Ernzerhof (GGA-PBE) exchange-correlation (XC) functional[48]was employed for geometry optimizations;van der Waals functional (vdW-DF-OB86) [49]was chosen for lattice parameter calculation and hybrid PBE0 functional [50]applied for electronic structure calculation. The virtual atoms ($Ag_{1-x} - Cu_x$) were modelled with the Optimized Norm-Conserving Vanderbilt (ONCV) pseudopotentials [51] using the VCA approach, where the mixing ratio *x*wasvaried from 0 to 1 in the step of 0.1.For the electron-ion interaction, ONCV pseudopotentials [51]were also employed for all calculations. In these calculations, the optimized kinetic cutoff energy of 100 Ry was set for plane-wave basis set expansion. The Monkhorst-Pack special [52] k-points sampling was set as $6 \times 6 \times 6$ for optimization and PBE0 band structure calculations. The convergence threshold was set at 10^{-10} eV, while the force on each atomwas less than 20 meV/Å after the relaxation of entire atomic positions.

3. Results and Discussion



Figure 1: Polyhedral view of $Cs_2AgInCl_6$ double perovskite (space group $Fm\overline{3}m$).

The host perovskite, CAIC, crystallizes in face-centred-cubic (fcc) phase with a space group of Fm $\overline{3}$ m and its crystalline structure are illustrated in Fig. 1. Within the framework of DFT, the van der Waals functional (vdW-DF-OB86) was used to accurately describe the lattice parameter and bulk modulus of the host perovskite by using the Birch-Murnaghan [53] fit of the total energy-unit cell volume data. The calculated lattice parameter for CAIC (10.514 Å) agrees well with the experimental value (10.469)[30]. The above procedure was repeated for Cs₂Ag_{1-x}Cu_xInCl₆ while varying the Cu content *x* from 0 to 1 in the step of 0.1. To ascertain the reliability of the VCA method, the lattice parameter and electronic bandgap of Cs₂Ag_{0.5}Cu_{0.5}InCl₆ are computed using a 2 × 2 × 2 supercell. The results obtained show good agreement; 10.441 Å (10.450 Å) and 0.41 eV (0.34 eV) for VCA method (supercell alloying method).

Figures 2 and 3 show the optimized lattice parameters and bulk moduli of CAIC:Cu solid solutions. As the composition of Cu increases, the lattice parameter decreases following a linearfunction, a(x) = 10.5128 - 0.1395x. This function satisfies the Vegard's law for lattice parameters. Conversely, the calculated bulk modulus increases quadratically following a second-order polynomial, $B(x) = 34.0636 + 1.4576x - 0.7576x^2$. With these results, it can be inferred that the incorporation of Cu into CAIC causes the crystal lattice to shrink, thus reinforcing the material stability.



Figure 2:Calculated lattice parameters as a function of Cu composition x in CAIC:Cu solid solutions, with linear fitting.



Figure 3:Bulk moduli as a function of Cu composition x in CAIC:Cu solid solutions with quadratic fittings.

The electronic band structures of CAIC and CAIC:Cu solid solutions are calculated using DFT based on the first-principles calculations.At first,GGA-PBE was employed as the exchange-correlation functional for the bandgap calculation, where a bandgap underestimation of 0.95 eV

was observed when compared with experimental value of 3.3 eV [30]. Table 1 shows the comparative results of the calculated bandgap with other experimental and theoretical results. To circumvent this underestimation and improve the accuracy of the bandgap, the hybrid PBE0 was used as the exchange-correlation functional where a bandgap value of 3.23 eV was obtained. The obtained result agrees well with experimental value of 3.3 eV (See Table 1).

Table 1:Calculated bandgap E_g of CAIC double perovskites using different exchange-correlation functionals compared with other experimental and theoretical results.

		This work			
Material		PBE	PBE0	Previous work	Expt.
CAIC (x = 0)	E _g (eV)	0.95	3.23	2.9-3.3[30],3.33[31]	3.3[30],

The nature of bandgap, as well as the locations of conduction band maximum (CBM) and valence band minimum (VBM), can be revealed via the electronic band structure. Figure 4depicts the electronic band structure of CAIC along some selected high symmetry points, which reflect that CAIC is a directbandgap DP with both CBM and VBM located at the gamma (Γ) point in the Brillouin zone.



Figure 4:Electronic band structure of CAIC using PBE0 functional.

From the aforementioned above, it is worth noting that the hybrid PBE0 functional can give the most reliable bandgap value for double perovskites. With this assertion, the hybrid PBE0 functional was then used to compute the electronic band structure of CAIC:Cu solid solutions. Figure 5 shows the variation tendency in the bandgap as the Cu composition increases. By interpolating the bandgaps to a polynomial function, the bandgaps decreasequadratically with a second-order polynomial function, $E(x) = 3.2698 - 0.6463x - 0.6936x^2$, with increasing Cu content (x). This function satisfied the Vegard's law with abandgap bowing parameter, b, of - 0.6936.In addition to this, the direct bandgap nature of the host perovskite remains unchanged despite the introduction of Cu-dopants. Bandgap bowing parameter (b) indicates the non-linearity of the bandgap to the composition, as well as the degree of fluctuation in the crystal

field. The results indicate enhancement in the light-harvesting ability of the materials owing to the reduction in the bandgap with increasing Cu content. Since the bandgap bowing parameter is very small, it indicates good miscibility between CAIC and CCIC (x = 1), and low compositional disorder.



Figure 5: Calculated bandgap of CAIC:Cu solid solutions with the polynomial fit. The experiment value for CAIC is indicated with the red dot.

4. Conclusion

In this work, the effect of Cu-doping on the structural and electronic properties of CAIC has been studied using first-principles DFT calculations and VCA approach. The ab-initio VCA method was used to model the solid solutions. The PBE0 functional was used for the band structure calculations after assessing the exchange-correlation functional of GGA-PBE. With increasing Cu contents, the crystal lattice shrinks following a linear function a(x) = 10.5128 -0.1395x, bulk modulus increases with a quadratic function of B(x) = 34.0636 + 1.4576x - $0.7576x^2$, while the bandgap decreases quadratically with a second-order polynomial function, $E(x) = 3.2698 - 0.6463x - 0.6936x^2$. The variation tendencies, as a result of Cu-doping, in the structural and electronic properties of the materials under study have shown Cu to be an efficient dopant in treating double perovskites. In conclusion, $Cs_2Ag_{1-x}Cu_xInCl_6$ (CAIC:Cu) solid solutions can be presented as potential candidates for photovoltaics and optoelectronics.

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